TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC367AP,TC74HC367AF TC74HC368AP,TC74HC368AF

Hex Bus Buffer

TC74HC367AP/AF Non-Inverted (3-state)

TC74HC368AP/AF Inverted (3-state)

The TC74HC367A and TC74HC368A are high speed CMOS 3-STATE BUS BUFFERs fabricated with silicon gate C²MOS technology.

They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

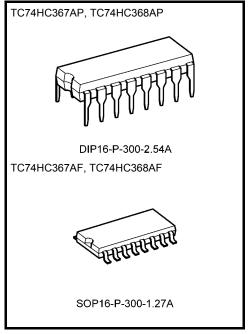
They contain six buffers; four buffers are controlled by an enable input ($\overline{G}1$), and the other two buffers are controlled by another enable input ($\overline{G}2$). The outputs of each buffer group are enabled when $\overline{G}1$ and/or $\overline{G}2$ inputs are held low; if held high, these outputs are in a high impedance state.

The TC74HC367A is a non-inverting output type, while the TC74HC368A is an inverting output type.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $t_{pd} = 11 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_{a} = 25 \text{°C}$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Output drive capability: 15 LSTTL loads
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 6 \text{ mA}$
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: VCC (opr) = 2 to 6 V
- Pin and function compatible with 74LS367/368

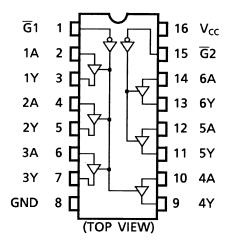


Weight

DIP16-P-300-2.54A : 1.00 g (typ.) SOP16-P-300-1.27A : 0.18 g (typ.)

Pin Assignment

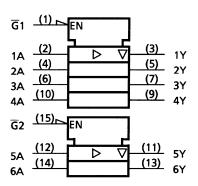
TC74HC367A



IEC Logic Symbol

TC74HC367A

HEX BUS BUFFER (3 - STATE)



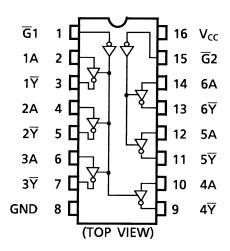
Truth Table

Inputs		Outputs					
G	An	Y (367A)	<u>Y</u> (368A)				
L	L	L	Н				
L	Н	Н	L				
Н	Х	Z	Z				

X: Don't care

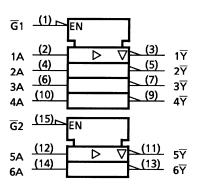
Z: High impedance

TC74HC368A



TC74HC368A

HEX BUS BUFFER (3 - STATE / INV.)





Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	–0.5 to 7	V
DC input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	−0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±35	mA
DC V _{CC} /ground current	Icc	±75	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to $65^{\circ}C$. From Ta = 65 to $85^{\circ}C$ a derating factor of -10 mW/°C shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2 to 6	V
Input voltage	V _{IN}	0 to V _{CC}	٧
Output voltage	V _{OUT}	0 to V _{CC}	٧
Operating temperature	T _{opr}	−40 to 85	°C
		0 to 1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0 to 500 (V _{CC} = 4.5 V)	ns
		0 to 400 (V _{CC} = 6.0 V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

3



Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition $\begin{array}{c} V_{CC} \\ (V) \end{array}$		Ta = 25°C			Ta = -40 to 85°C		Unit	
					Min	Тур.	Max	Min	Max	Offic
		_		2.0	1.50	_	_	1.50	_	
High-level input voltage	V_{IH}			4.5	3.15	_	_	3.15	_	V
				6.0	4.20	—	_	4.20	_	
				2.0	_	_	0.50	_	0.50	
Low-level input voltage	V _{IL}	_		4.5	_	_	1.35	_	1.35	V
ŭ						_	1.80	_	1.80	
	Voн	V _{IN} = V _{IH} or V _{IL}		2.0	1.9	2.0	_	1.9	_	
			$I_{OH} = -20 \mu A$	4.5	4.4	4.5		4.4	_	
High-level output voltage				6.0	5.9	6.0	_	5.9	_	_ V
			$I_{OH} = -6 \text{ mA}$	4.5	4.18	4.31	_	4.13	_	
			$I_{OH} = -7.8 \text{ mA}$	6.0	5.68	5.80	_	5.63	_	
	V _{OL}	V _{IN} = V _{IH} or V _I L	I _{OL} = 20 μA	2.0	_	0.0	0.1	_	0.1	
				4.5	_	0.0	0.1		0.1	
Low-level output voltage				6.0		0.0	0.1	_	0.1	V
			I _{OL} = 6 mA	4.5	_	0.17	0.26	_	0.33	
			I _{OL} = 7.8 mA	6.0		0.18	0.26	_	0.33	
3-state output off-state current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		6.0	_	_	±0.5	_	±5.0	μА
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0		_	±0.1		±1.0	μА
Quiescent supply current	Icc	$V_{IN} = V_C$	V _{IN} = V _{CC} or GND			_	4.0	_	40.0	μА



AC Characteristics (input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
Characteristics	Symbol		CL (pF)	V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
	4			2.0	_	25	60	_	75	
Output transition time	t _{TLH}	_	50	4.5	_	7	12	_	15	ns
	t _{THL}			6.0	_	6	10	_	13	
				2.0	_	36	95	_	120	
			50	4.5	_	12	19	_	24	
Propagation delay	t_{pLH}			6.0	_	10	16	_	20	
time	t_{pHL}	_		2.0	_	40	130	_	165	ns
			150	4.5	_	16	26	_	33	
				6.0	_	14	22	_	28	
	t _{pZL} t _{pZH}	$R_L = 1 \text{ k}\Omega$		2.0	_	36	120	_	150	- ns
			50	4.5	_	12	24	_	30	
Output anabla tima				6.0	_	10	20	_	26	
Output enable time			150	2.0	_	40	160	_	200	
				4.5	_	16	32	_	40	
				6.0	_	14	27	_	34	
	t _{pLZ}	$R_L = 1 \text{ k}\Omega$	50	2.0	_	35	120	_	150	ns
Output disable time				4.5	_	15	24	_	30	
				6.0	_	13	20	_	26	
Input capacitance	C _{IN}	_			_	5	10	_	10	pF
Output capacitance	C _{OUT}	_			_	10	_	_	_	pF
Power dissipation capacitance	C _{PD}	TC74HC367A			_	36	_	_	_	
	(Note)	TC74HC368A			_	30	_	_	_	pF

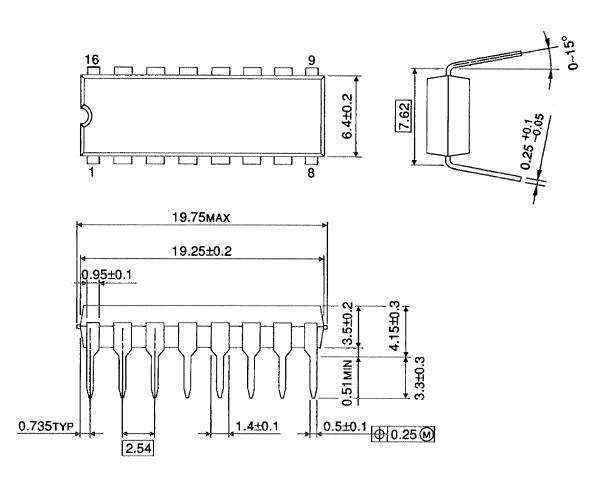
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6$ (per bit)

Package Dimensions

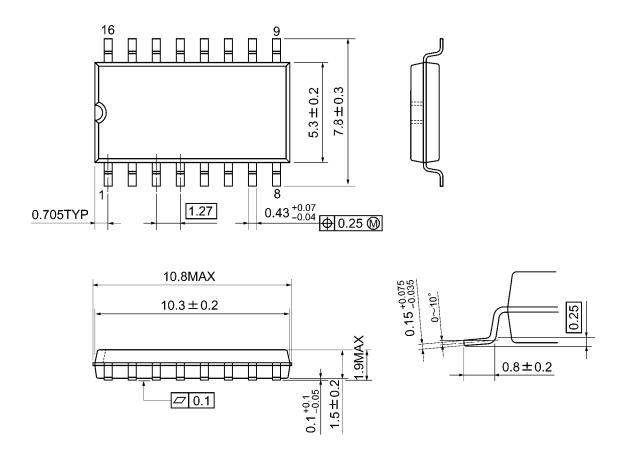
DIP16-P-300-2.54A Unit: mm



Weight: 1.00 g (typ.)

Package Dimensions

SOP16-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

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